## **Smart High-Side Power Switch**

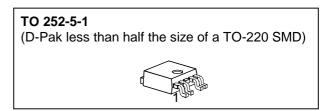
One Channel:  $60m\Omega$ 

**Status Feedback** 

#### **Product Summary**

| On-state Resistance  | R <sub>ON</sub>     | $60 \text{m}\Omega$ |
|----------------------|---------------------|---------------------|
| Operating Voltage    | $V_{bb(on)}$        | 4.7541V             |
| Nominal load current | I <sub>L(NOM)</sub> | 7.0A                |
| Current limitation   | I <sub>L(SCr)</sub> | 17A                 |

#### **Package**



#### **General Description**

- N channel vertical power MOSFET with charge pump, ground referenced CMOS compatible input and diagnostic feedback, monolithically integrated in Smart SIPMOS® technology.
- Fully protected by embedded protection functions

#### **Applications**

- μC compatible high-side power switch with diagnostic feedback for 5V, 12V and 24V grounded loads
- All types of resistive, inductive and capacitve loads
- Most suitable for loads with high inrush currents, so as lamps
- · Replaces electromechanical relays, fuses and discrete circuits

#### **Basic Functions**

- Very low standby current
- CMOS compatible input
- Improved electromagnetic compatibility (EMC)
- · Fast demagnetization of inductive loads
- Stable behaviour at undervoltage
- Wide operating voltage range
- Logic ground independent from load ground

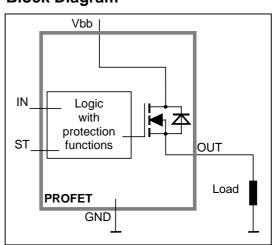
#### **Protection Functions**

- Short circuit protection
- Overload protection
- Current limitation
- Thermal shutdown
- Overvoltage protection (including load dump) with external resistor
- Reverse battery protection with external resistor
- Loss of ground and loss of V<sub>bb</sub> protection
- Electrostatic discharge protection (ESD)

#### **Diagnostic Function**

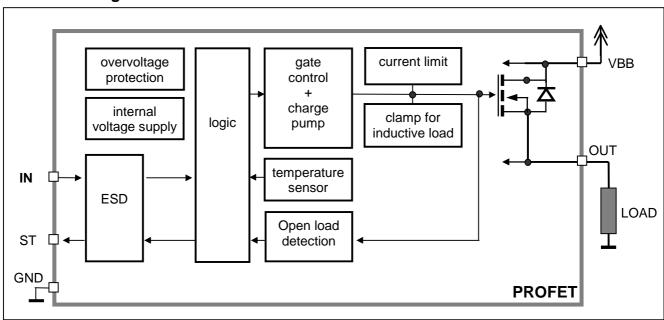
- Diagnostic feedback with open drain output
- Open load detection in ON-state
- · Feedback of thermal shutdown in ON-state

### **Block Diagram**





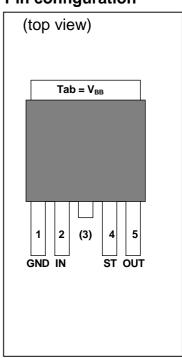
## **Functional diagram**



#### **Pin Definitions and Functions**

| Pin | Symbol          | Function   |
|-----|-----------------|--|
| 1   | GND             | Logic ground   |
| 2   | IN              | Input, activates the power switch in case of logical high signal |
| 3   | V <sub>bb</sub> | Positive power supply voltage The tab is shorted to pin 3        |
| 4   | ST              | Diagnostic feedback, low on failure                              |
| 5   | OUT             | Output to the load   |
| Tab | V <sub>bb</sub> | Positive power supply voltage The tab is shorted to pin 3        |

## Pin configuration





## **Maximum Ratings** at $T_j = 25$ °C unless otherwise specified

| Parameter   | Symbol                                | Values            | Unit |
|---|---------------------------------------|-------------------|------|
| Supply voltage (overvoltage protection see page 4)  | $V_{ m bb}$                           | 43                | V    |
| Supply voltage for full short circuit protection $T_{\rm j  Start}$ =-40+150°C  | $V_{ m bb}$                           | 24                | V    |
| Load dump protection <sup>1)</sup> $V_{\text{LoadDump}} = V_{\text{A}} + V_{\text{S}}, V_{\text{A}} = 13.5 \text{ V}$ $R_{\text{I}}^{2} = 2 \Omega, R_{\text{L}} = 4.0 \Omega, t_{\text{d}} = 400 \text{ ms}, IN= \text{low or high}$ | V <sub>Load dump</sub> <sup>3</sup> ) | 60                | V    |
| Load current (Current limit, see page 5)  | <i>I</i> ∟                            | self-limited      | Α    |
| Operating temperature range   | T <sub>j</sub>                        | -40+150           | °C   |
| Storage temperature range   | T <sub>stg</sub>                      | -55+150           |      |
| Power dissipation (DC), T <sub>C</sub> ≤ 25 °C  | P <sub>tot</sub>                      | 75                | W    |
| Maximal switchable inductance, single pulse $V_{bb} = 12V$ , $T_{J,start} = 150$ °C, $T_{C} = 150$ °C const. (See diagram on page 8) $I_{L(ISO)} = 7$ A, $R_{L} = 0$ $\Omega$ ; $E^{4)}_{AS} = 0.19$ J:                               | Zı                                    | 5.6               | mH   |
| Electrostatic discharge capability (ESD) IN: (Human Body Model) ST: out to all other pins shorted: acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993; R=1.5kΩ; C=100pF   | V <sub>ESD</sub>                      | 1.0<br>4.0<br>8.0 | kV   |
| Input voltage (DC)  | $V_{IN}$                              | -10 +16           | V    |
| Current through input pin (DC)  | I <sub>IN</sub>                       | ±2.0              | mA   |
| Current through status pin (DC)   | <i>I</i> <sub>ST</sub>                | ±5.0              |      |
| see internal circuit diagrams page 7  |                                       |                   |      |

## **Thermal Characteristics**

| Parameter and Conditions |                                | Symbol              | Values |     |      | Unit |
|--------------------------|--------------------------------|---------------------|--------|-----|------|------|
|                          |                                |                     | min    | typ | max  |      |
| Thermal resistance       | chip - case:                   | $R_{\mathrm{thJC}}$ |        |     | 1.67 | K/W  |
|                          | junction - ambient (free air): | $R_{thJA}$          |        |     | 75   |      |
|                          | device on pcb <sup>5</sup> ):  |                     |        | 42  |      |      |

 $<sup>^{1)}</sup>$  Supply voltages higher than  $V_{bb(AZ)}$  require an external current limit for the GND and status pins (a 150 $\Omega$ resistor for the GND connection is recommended).

 $R_{\rm I}$  = internal resistance of the load dump test pulse generator  $V_{\rm Load\ dump}$  is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839  $E_{\rm AS}$  is the maximum inductive switch-off energy

Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70µm thick) copper area for V<sub>bb</sub> connection. PCB is vertical without blown air.



#### **Electrical Characteristics**

| Parameter and Conditions  | Symbol |     | Values | ;   | Unit |
|---|--------|-----|--------|-----|------|
| at $T_j = -40 + 150$ °C, $V_{bb} = 12$ V unless otherwise specified |        | min | typ    | max |      |

#### **Load Switching Capabilities and Characteristics**

| $R_{\text{ON}}$         |  | 50  | 60   | $m\Omega$   |
|-------------------------|--|---|--|---|
| :                       |  | 100   | 120  |   |
|                         |  |   |  |   |
|                         |  |   |  |   |
| $I_{L(ISO)}$            | 5.8  | 7.0   |  | Α   |
| I <sub>L(GNDhigh)</sub> |  |   | 2  | mA  |
| , , ,                   |  |   |  |   |
|                         |  |   |  |   |
| :                       | 30   | 100   | 200  | μs  |
| $t_{\rm off}$           | 30   | 100   | 200  |   |
|                         |  |   |  |   |
| dV/dt <sub>on</sub>     | 0.1  |   | 1  | V/μs  |
|                         |  |   |  |   |
| -d V/dt <sub>off</sub>  | 0.1  |   | 1  | V/μs  |
|                         |  |   |  |   |
|                         | $I_{L(ISO)}$ $I_{L(GNDhigh)}$ : $t_{on}$ : $t_{off}$ | I <sub>L(ISO)</sub>   5.8   I <sub>L(GNDhigh)</sub>       30   30     dV/dt <sub>on</sub>   0.1 | IL(ISO)       5.8       7.0         IL(GNDhigh)           ton       30       100         toff       30       100         dV/dton       0.1 | $\begin{array}{c ccccccccccccccccccccccccccccccccccc$ |

## **Operating Parameters**

| Operating voltage  | $T_{\rm j} = -40$  | $V_{\rm bb(on)}$     | 4.75 |     | 41  | V  |
|--|--|----------------------|------|-----|-----|----|
|  | <i>T</i> j =+25+150°C:   | , ,                  |      |     | 43  |    |
| Overvoltage protection <sup>6)</sup>                         | $T_{i} = -40^{\circ}C$ :   | $V_{\rm bb(AZ)}$     | 41   |     | -   | V  |
| <i>I</i> <sub>bb</sub> =40 mA                                | <i>T</i> j =25+150°C:  |                      | 43   | 47  | 52  |    |
| Standby current (pin 3) 7)                                   | <i>T</i> <sub>i</sub> =-40+25°C:<br><i>T</i> <sub>i</sub> = 150°C: | I <sub>bb(off)</sub> |      | 5   | 0   | μΑ |
| $V_{\rm IN}$ =0; see diagram on page 9                       | <i>T</i> <sub>j</sub> = 150°C:                                     |                      |      |     | 25  |    |
| Off-State output current (included in I <sub>bb(off)</sub> ) |  | I <sub>L(off)</sub>  |      | 1   | 10  | μΑ |
| VIN=0  |  |                      |      |     |     |    |
| Operating current 8), V <sub>IN</sub> =5 V                   |  | I <sub>GND</sub>     |      | 0.8 | 1.5 | mA |
|  |  |                      |      |     |     |    |

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Supply voltages higher than V<sub>bb(AZ)</sub> require an external current limit for the GND and status pins (a 150Ω resistor for the GND connection is recommended. See also V<sub>ON(CL)</sub> in table of protection functions and circuit diagram page 7.

Measured with load

<sup>&</sup>lt;sup>8)</sup> Add  $I_{ST}$ , if  $I_{ST} > 0$ , add  $I_{IN}$ , if  $V_{IN} > 5.5 \text{ V}$ 

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| Parameter and Conditions   |  | Symbol                    | Values         |                |                | Unit |
|--|--|---------------------------|----------------|----------------|----------------|------|
| at $T_j = -40 + 150$ °C, $V_{bb} = 12$ V unless other                                  | wise specified   |                           | min            | typ            | max            |      |
| Protection Functions   |  |                           |                |                |                |      |
| Current limit (pin 3 to 5)   |  | I <sub>L(lim)</sub>       |                |                |                |      |
| (see timing diagrams on page 11)   | $T_{\rm j}$ =-40°C:<br>$T_{\rm j}$ =25°C:<br>$T_{\rm j}$ =+150°C:  |                           | 21<br>17<br>12 | 28<br>22<br>16 | 36<br>31<br>24 | А    |
| Repetitive short circuit shutdown cur  | rent limit   | I <sub>L(SCr)</sub>       |                |                |                |      |
| $T_{\rm j}=T_{\rm jt}$ (see timing diagrams, page 11)                                  |  |                           |                | 17             |                | Α    |
| Thermal shutdown time <sup>9</sup>   | $T_{\rm j,start} = 25^{\circ}\rm C$ :                              | t <sub>off(SC)</sub>      |                | 7.5            |                | ms   |
| (see timing diagrams on page 11)   |  |                           |                |                |                |      |
| Output clamp (inductive load switch at $V_{\rm OUT} = V_{\rm bb}$ - $V_{\rm ON(CL)}$   | off) $I_L = 40 \text{ mA}$ :                                       | $V_{ m ON(CL)}$           | 41<br>43       | 47             | 52             | V    |
| Thermal overload trip temperature  |  | $T_{\rm jt}$              | 150            |                |                | °C   |
| Thermal hysteresis   |  | $\Delta T_{\rm jt}$       |                | 10             |                | K    |
| Reverse battery (pin 3 to 1) 10)   |  | -V <sub>bb</sub>          |                |                | 32             | V    |
| Reverse battery voltage drop ( $V_{out} > V_{L} = -2 \text{ A}$                        | √ <sub>bb)</sub> <sup>11</sup> )<br><i>T</i> <sub>i</sub> =150 °C: | -V <sub>ON(rev)</sub>     |                | 600            |                | mV   |
| Diagnostic Characteristics  Open load detection current (on-condition)                 |  | I <sub>L (OL)</sub>       | 10             |                | 500            | mA   |
| Input and Status Feedback <sup>12</sup> ) Input resistance see circuit page 7          |  | Rı                        | 2.5            | 3.5            | 6              | kΩ   |
| Input turn-on threshold voltage  |  | $V_{IN(T+)}$              | 1.7            |                | 3.2            | V    |
| Input turn-off threshold voltage   |  | $V_{\text{IN(T-)}}$       | 1.5            |                |                | V    |
| Input threshold hysteresis   |  | $\Delta V_{\text{IN(T)}}$ |                | 0.5            |                | V    |
| Off state input current (pin 2), $V_{IN} = 0.4 \text{ V}$                              |  | I <sub>IN(off)</sub>      | 1              |                | 50             | μΑ   |
| On state input current (pin 2), $V_{IN} = 5 \text{ V}$                                 |  | I <sub>IN(on)</sub>       | 20             | 50             | 90             | μΑ   |
| Delay time for status with open load after switch off (see timing diagrams on page 11) |  | t <sub>d(ST OL4)</sub>    | 100            | 520            | 900            | μs   |
| Status output (open drain)   |  |                           |                |                |                |      |
| Zener limit voltage  | $I_{ST} = +1.6 \text{ mA}$ :                                       | $V_{\rm ST(high)}$        | 5.4            | 6.1            | <b></b>        | V    |
| ST low voltage   | $I_{ST} = +1.6 \text{ mA}$ :                                       | $V_{\rm ST(low)}$         |                |                | 0.4            |      |

Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70μm thick) copper area for V<sub>bb</sub> connection. PCB is vertical without blown air.

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Requires 150 Ω resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Note that the power dissipation is higher compared to normal operating conditions due to the voltage drop across the intrinsic drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 3 and circuit page 7).

Specified by design, not tested

<sup>12)</sup> If a ground resistor R<sub>GND</sub> is used, add the voltage drop across this resistor.



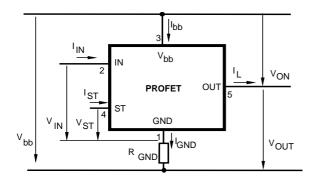
## **Truth Table**

|           | Input | Output | Status    |
|-----------|-------|--------|-----------|
|           | level | level  | BTS 428L2 |
| Normal    | L     | L      | Н         |
| operation | Н     | Н      | Н         |
| Open load | L     | Z      | Н         |
| _         | Н     | Н      | L         |
| Overtem-  | L     | L      | Н         |
| perature  | Н     | L      | L         |

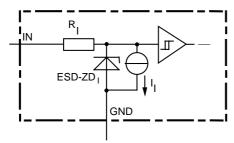
L = "Low" Level H = "High" Level X = don't care Z = high impedance, potential depends on external circuit Status signal after the time delay shown in the diagrams (see fig 5. page 11)

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#### **Terms**

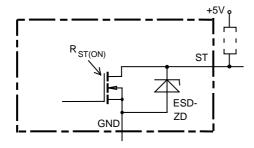


#### Input circuit (ESD protection)



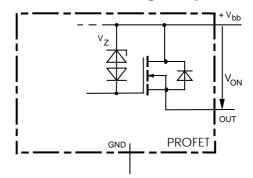
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

### Status output



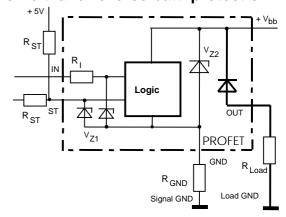
ESD-Zener diode: 6.1 V typ., max 5.0 mA; RST(ON) < 375  $\Omega$  at 1.6 mA. The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

#### Inductive and overvoltage output clamp



Von clamped to 47 V typ.

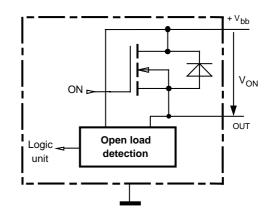
#### Overvolt. and reverse batt. protection



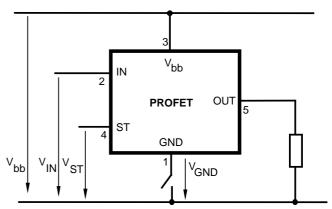
 $V_{Z1}$  = 6.1 V typ.,  $V_{Z2}$  = 47 V typ.,  $R_{GND}$  = 150 Ω,  $R_{ST}$ = 15 kΩ,  $R_{I}$ = 3.5 kΩ typ.

#### Open-load detection in on-state

Open load, if  $V_{ON} < R_{ON} \cdot I_{L(OL)}$ ; IN high



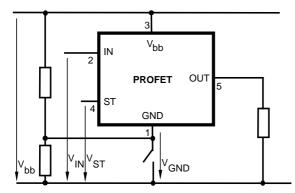
#### **GND** disconnect



Any kind of load. In case of Input=high is  $V_{OUT} \approx V_{IN} - V_{IN(T+)}$ . Due to  $V_{GND} > 0$ , no  $V_{ST} = low$  signal available.

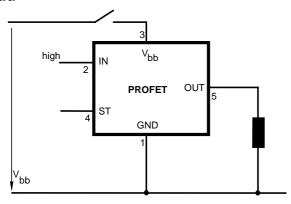
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#### **GND** disconnect with GND pull up



Any kind of load. If  $V_{GND} > V_{IN} - V_{IN(T+)}$  device stays off Due to  $V_{GND} > 0$ , no  $V_{ST} =$  low signal available.

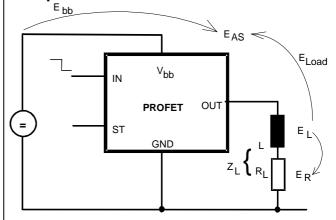
# V<sub>bb</sub> disconnect with energized inductive load



For inductive load currents up to the limits defined by  $Z_L$  (max. ratings and diagram on page 8) each switch is protected against loss of  $V_{bb}$ .

Consider at your PCB layout that in the case of Vbb disconnection with energized inductive load all the load current flows through the GND connection.

# Inductive Load switch-off energy dissipation



Energy stored in load inductance:

$$E_{\rm L} = \frac{1}{2} \cdot {\rm L} \cdot {\rm I}_{\rm L}^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

$$E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} \cdot i_L(t) dt$$

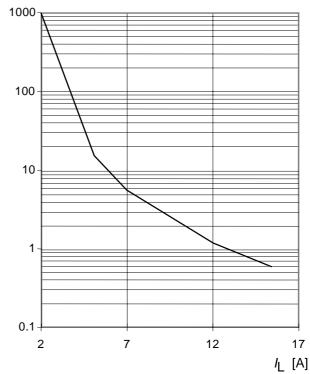
with an approximate solution for  $R_L > 0\Omega$ :

$$E_{\text{AS}} = \frac{I_{\text{L}} \cdot L}{2 \cdot R_{\text{L}}} \cdot \left( V_{\text{bb}} + |V_{\text{OUT(CL)}}| \right) \cdot \ln \left( 1 + \frac{I_{\text{L}} \cdot R_{\text{L}}}{|V_{\text{OUT(CL)}}|} \right)$$

# Maximum allowable load inductance for a single switch off

$$L = f(I_L); T_{j,start} = 150^{\circ}C, T_C = 150^{\circ}C \text{ const.},$$
  
$$V_{bb} = 12 \text{ V}, R_L = 0 \Omega$$

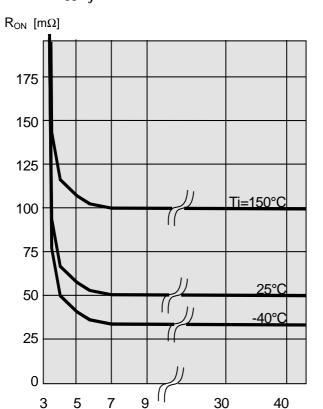
 $Z_L$  [mH]





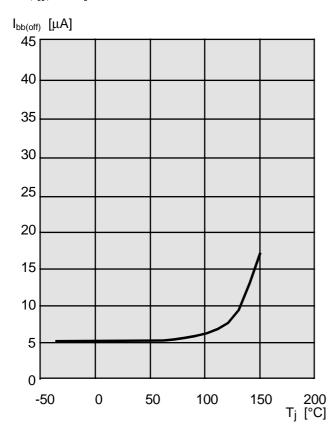
## Typ. on-state resistance

 $R_{ON} = f(V_{bb}, T_i)$ ;  $I_L = 2 \text{ A}$ , IN = high



## Typ. standby current

 $I_{bb(off)} = f(T_j); V_{bb} = 9...34 \text{ V, IN1,2} = \text{low}$ 

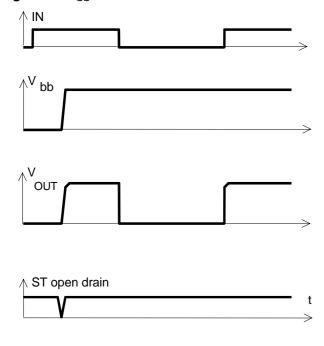


V<sub>bb</sub> [V]



## **Timing diagrams**

Figure 1a: V<sub>bb</sub> turn on:



proper turn on under all conditions

**Figure 2a:** Switching a resistive load, turn-on/off time and slew rate definition:

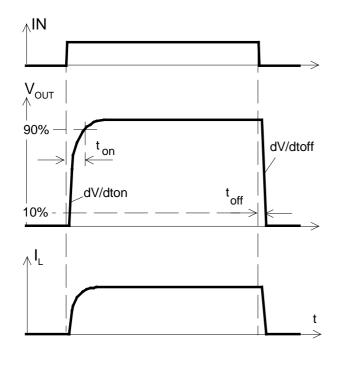
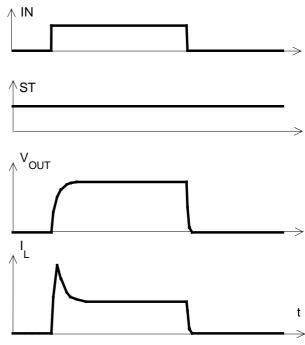
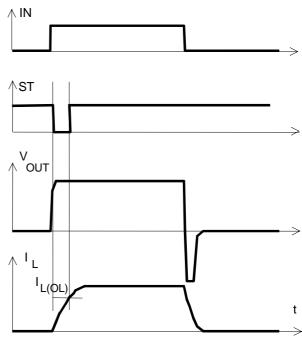


Figure 2b: Switching a lamp,



The initial peak current should be limited by the lamp and not by the initial short circuit current  $I_{L(SCp)}=30~A$  typ. of the device.

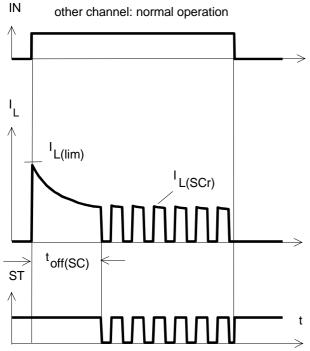
Figure 2c: Switching an inductive load



\*) if the time constant of load is too large, open-load-status may occur

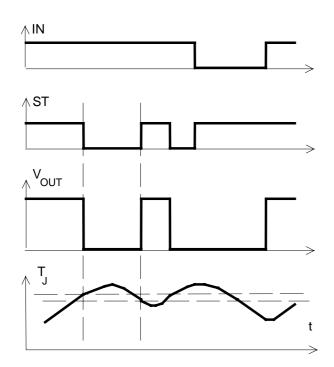
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Figure 3a: Short circuit shut down by overtemperature, reset by cooling



Heating up of the chip may require several milliseconds, depending on external conditions

**Figure 4a:** Overtemperature: Reset if  $T_j < T_{jt}$ 



**Figure 5a:** Open load: detection in ON-state, open load occurs in on-state

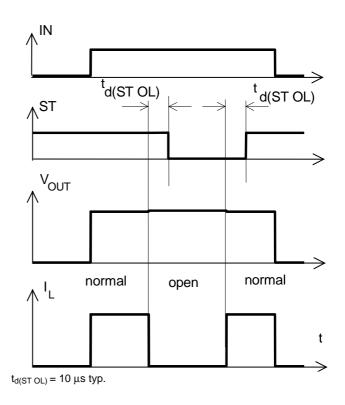
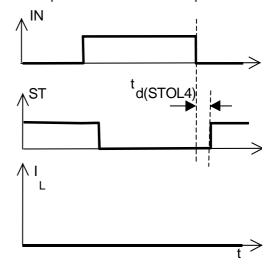


Figure 5b: Open load: turn on/off to open load



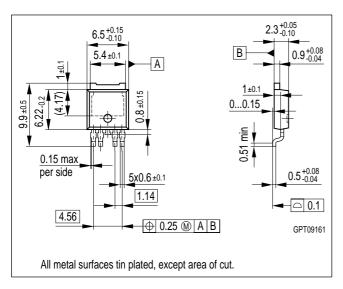
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## **Package and Ordering Code**

All dimensions in mm

**Dpak-5 Pin: P-TO252-5-1** 

| Sales code    | BTS428L2        |
|---------------|-----------------|
| Ordering code | Q67060-S7403-A2 |



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